Thyristor Semiconductor Device - Page 1 of 1



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	losure Material:
Me	
	erall Length:
	50 inches
	erall Diameter:
	00 inches
Мо	unting Facility Quantity:
1	
	ernal Configuration:
	action contact
	unting Method:
	eaded stud
	erall Width Across Flats:
	62 inches
	read Size:
	50 inches
	niconductor Material:
	con
	tage Rating In Volts Per Characteristic:
	0.0 off-state voltage, dc
Cu	rrent Rating Per Characteristic:
25.	00 milliamperes forward current, total rms preset
	ximum Operating Tempurature Per Measurement Point:
	0.0 degrees celsius junction
Spo	ecial Features:
	ction pattern arrangement: pnpn
	read Series Designator:
Unf	
	minal Type And Quantity:
	nreaded stud and 2 tab, solder lug
	elf Life:
N/a	
Uni	it Of Measure:
	militarization:
No	
Fiiç	
A1′	10a0